L Number	Hits	Search Text	DB	Time stamp
-	2	("20020042201").PN.	USPAT;	2003/04/28 09:42
i	i		US-PGPUB;	
1			EPO; JPO;	
i	1		DERWENT;	
İ	1 2156		IBM_TDB	
-	3156	bpsg and cmp and (darc or hard adj oxide	USPAT;	2003/04/29 07:54
		or nitride or oxynitride or siN or sion)	US-PGPUB;	
F			EPO; JPO;	
			DERWENT;	İ
_	599	bpsg same cmp same (darc or hard adj oxide	IBM_TDB USPAT;	2003/04/28 09:45
	!	or nitride or oxynitride or siN or sion)	US-PGPUB;	2003/04/28 09:45
•	1	or micraco or oxymiciae or six or sion,	EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	100	bpsg with cmp with (darc or hard adj oxide	USPAT;	2003/04/28 10:08
		or nitride or oxynitride or siN or sion)	US-PGPUB;	
			EPO; JPO;	
ĺ	1		DERWENT;	
	1		IBM_TDB	
-	113	(metal or conductive or electrode or	USPAT;	2003/04/28 10:09
i	1	tungsten or polysilicon) with bpsg same	US-PGPUB;	
	1	cmp same (darc or hard adj oxide or	EPO; JPO;	
		nitride or oxynitride or siN or sion)	DERWENT;	
i _	42	(metal or conductive or electrode or	IBM_TDB	2002/04/02 10 10
	42	tungsten or polysilicon) with bpsg with	USPAT;	2003/04/28 10:19
	ł	cmp with (darc or hard adj oxide or	US-PGPUB; EPO; JPO;	
i	1	nitride or oxynitride or siN or sion)	DERWENT;	
		The state of the s	IBM TDB	
-	2160	(438/970,959, 692, 693, 760, "698").CCLS.	USPAT;	2003/04/29 07:54
		, , , , , , , , , , , , , , , , , , , ,	US-PGPUB;	2003/01/23 01:31
			EPO; JPO;	
			DERWENT;	
			IBM TDB	1
-	0	("(cmp or polishing) and 7").PN.	USPĀT;	2003/04/28 10:22
			US-PGPUB;	
			EPO; JPO;	
}	j		DERWENT;	
_	1707	(cmm or moliching) and ((420/070 050 000	IBM_TDB	0000/04/00 10 01
. –	1/8/	(cmp or polishing) and ((438/970,959, 692, 693, 760, "698").CCLS.)	USPAT;	2003/04/28 10:31
İ	İ	093, 700, 098).CCL3.)	US-PGPUB; EPO; JPO;	
			DERWENT;	
!			IBM TDB	
- '	288	((cmp or polishing) and ((438/970,959,	USPĀT;	2003/04/28 10:25
		692, 693, 760, "698").CCLS.)) and (bpsg	US-PGPUB;	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1
i		and (darc or hard adj oxide or nitride or	EPO; JPO;	
ļ		oxynitride or siN or sion))	DERWENT;	
		<u>,,,</u>	IBM_TDB	
1 -	283	(((cmp or polishing) and ((438/970,959,	USPAT;	2003/04/28 10:31
1	!	692, 693, 760, "698").CCLS.)) and (bpsg	US-PGPUB;	
		and (darc or hard adj oxide or nitride or oxynitride or siN or sion))) not ((metal	EPO; JPO;	
		or conductive or electrode or tungsten or	DERWENT;	
		polysilicon) with bpsg with cmp with (darc	IBM_TDB	
		or hard adj oxide or nitride or oxynitride		
		or siN or sion))		
-	290	(438/754).CCLS.	USPAT;	2003/04/28 10:31
1			US-PGPUB;	
1			EPO; JPO;	
	ļ		DERWENT;	
			IBM_TDB	
<u> </u>	290	((438/754).CCLS.) ((cmp or polishing) and	USPAT;	2003/04/28 10:32
		((438/754).CCLS.))	US-PGPUB;	
	j		EPO; JPO;	
		•	DERWENT;	
	<u></u>		IBM_TDB	

-	364	((((cmp or polishing) and ((438/970,959,	USPAT;	2003/04/28 10:32
	İ	692, 693, 760, "698").CCLS.)) and (bpsg	US-PGPUB;	
ļ	-	and (darc or hard adj oxide or nitride or	EPO; JPO;	
	İ	oxymitride or siN or sion))) not ((metal	DERWENT;	
		or conductive or electrode or tungsten or	IBM_TDB	
		polysilicon) with bpsg with cmp with (darc		
		or hard adj oxide or nitride or oxynitride		
		or siN or sion))) ((cmp or polishing) and		
1		((438/754).CCLS.))		
-	95	(cmp or polishing) and ((438/754).CCLS.)	USPAT;	2003/04/28 10:32
	1		US-PGPUB;	1
1	1		EPO; JPO;	
1	ŀ		DERWENT;	
i	1 0000		IBM_TDB	
	8923	bpsg and (darc or hard adj oxide or	USPAT;	2003/04/29 07:54
		nitride or oxynitride or siN or sion)	US-PGPUB;	
			EPO; JPO;	
1	1		DERWENT;	
	01.67	(420 /070 050 600 600 760 600)	IBM_TDB	
-	2167	(438/970,959,692,693,760,698).CCLS.	USPAT;	2003/04/29 07:58
			US-PGPUB;	
			EPO; JPO;	
	1		DERWENT;	
	0025	/420/070 050 600 600 560 600 545	IBM_TDB	
_	2935	(438/970,959,692,693,760,698,745,754).CCLS.		2003/04/29 08:00
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
1	1001	//420/070 050 600 600 760 600 745 754) 607	IBM_TDB	
-	1961	((438/970,959,692,693,760,698,745,754).CCLS		2003/04/29 08:00
	1	and (cmp or polishing)	US-PGPUB;	
	1		EPO; JPO;	
			DERWENT;	
	. 217	1 ///420/070 050 600 600 760 600 767 756	IBM_TDB	
-	31/	(((438/970,959,692,693,760,698,745,754).CCL		2003/04/29 09:25
		and (cmp or polishing)) and (bpsg and	US-PGPUB;	
		(darc or hard adj oxide or nitride or	EPO; JPO;	
		oxynitride or siN or sion))	DERWENT;	
	י ברח ו	(1 a.c. a.d. # 11:11 a.d. d. d. d. a.t. a.t. a.t. a.t. a.t.	IBM_TDB	0000 (01 (00 05
, -) 553 l	(low adj "k" adj dielectric) same (darc or	USPAT;	2003/04/29 09:28
i	ı İ	nitride or sion)	US-PGPUB;	
	;		EPO; JPO;	
: 	1		DERWENT;	
L			IBM_TDB	